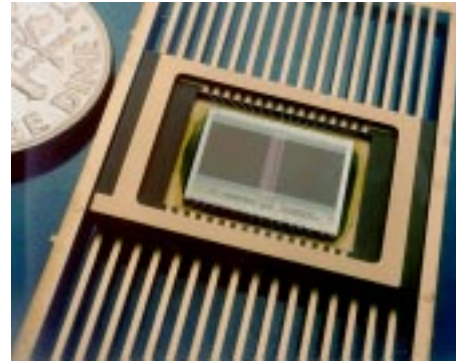


Radiation-Hardened Microcircuits

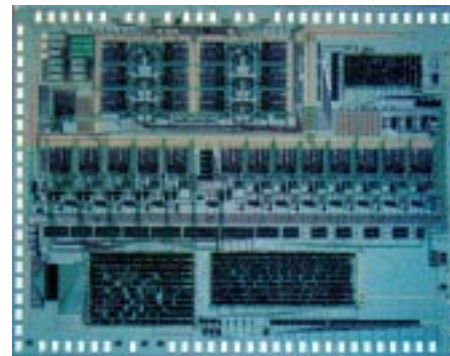
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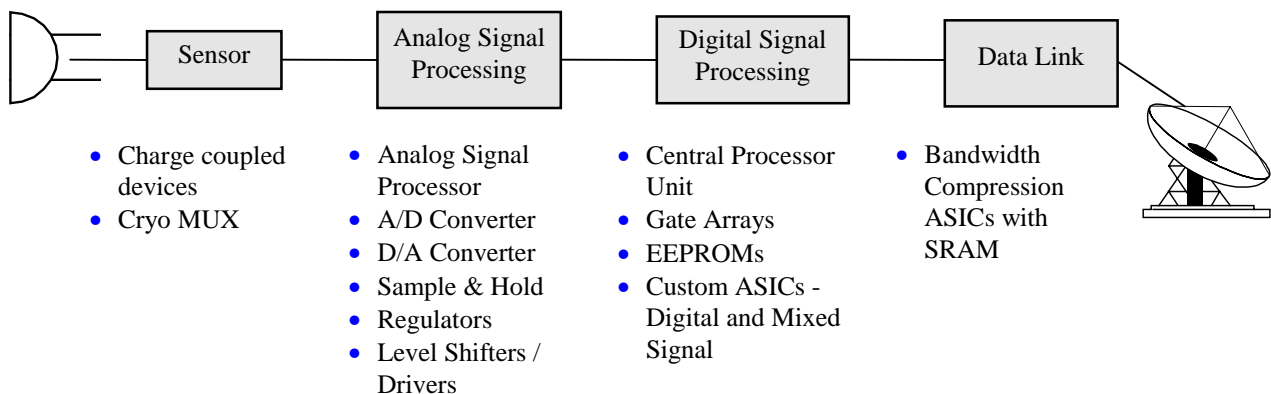


Rad-Hard 256K EEPROM



Rad-Hard 11 bit @ 5 MHz and 5 mW/MHz A/D Converter

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